

PI90LV179 3.3V LVDS High-Speed Differential Line Driver and Receiver

Features

- Signaling Rates >660 Mbps (330 MHz)
- Single 3.3V Power Supply Design
- Driver:
 - ±350mV Differential Swing into a 100-ohm load
 - Propogation Delay of 1.5ns Typ.
 - Low Voltage TTL (LVTTL) Inputs are 5V Tolerant
- Receiver:
 - Accepts ±50mV (min.) Differential Swing with up to 2.0V ground potential difference
 - Propagation Delay of 3.3ns Typ.
 - Low Voltage TTL (LVTTL) Outputs
 - Open, Short, and Terminated Fail Safe
- Industrial Temperature Operating Range: -40°C to 85°C
- Meets or Exceeds IEEE 1596.3 SCI Standard
- Meets or Exceeds ANSI/TIA/EIA-644 LVDS Standard
- Bus terminal ESD = 2KV HBM
- Packaging (Pb-free & Green available):
 8-pin SOIC or MSOP

Description

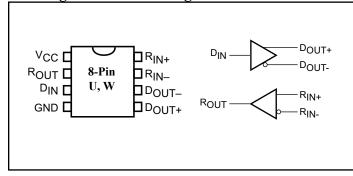
The PI90LV179is a differential line driver and receiver (transceiver) that is compliant with the IEEE 1596.3 SCI and ANSI/ TIA/EIA-644 LVDS standards. This device uses low-voltage differential signaling (LVDS) to achieve data rates in excess of 660 Mbps while being less susceptible to noise than single-ended transmission.

The driver translates a low-voltage TTL/CMOS input into a low-voltage (350mV typical) differential output signal. The receiver translates a differential 350mV input signal to a 3V CMOS output level.

Applications

Applications include point-to-point and multidrop baseband data transmission over a controlled impedance media of approximately 100 ohms. These include intra-system connections via printed circuit board traces or cables, hubs and routers for data communi- cations; PBXs, switches, repeaters and base stations for telecommunications and other applications such as digital cameras, printers and copiers.

Pin Diagram & Block Diagram



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Function Tables

PI90LV179 Receiver

Inputs	Output
$\mathbf{V}_{\mathrm{ID}} = \mathbf{V}_{\mathrm{RIN}^+} - \mathbf{V}_{\mathrm{RIN}^-}$	Н
$V_{ID} \ge 50 mV$	Н
$-50 \text{mV} < \text{V}_{\text{ID}} < 50 \text{mV}$?
$V_{ID} \leq -50 mV$	L
open	Н

PI90LV179 Driver

Input	Outŗ	out
D _{IN}	D _{OUT+}	D _{OUT-}
L	L	Н
Н	Н	L
open	L	Н

Notes:

H = High Level, L = Low Level, ? = Indeterminate, Z = High-Impedance, X = Don't Care

Pin Descriptions

Pin Name	Description
D _{IN}	TTL/CMOS driver input pin
D _{OUT+}	Non-inverting driver output pin
D _{OUT-}	Inverting driver output pin
R _{OUT}	TTL/CMOS receiver output pin
R _{IN+}	Non-inverting receiver input pin
R _{IN-}	Inverting receiver input pin
GND	Ground pin
V _{CC}	Positive power supply pin, $+3.3V \pm 10\%$

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Absolute Maximum Ratings

Supply Voltage (V _{cc})–0.5V to +4.0V
Driver
Input Voltage (D_{IN}) $-0.3V$ to $(Vcc + 0.3V)$
Output Voltage (D _{OUT+} , D _{OUT-})0.3V to +3.9V
Short Circuit Duration (D _{OUT+} , D _{OUT-})Continuous
Receiver
Input Voltage (R_{IN+} , R_{IN-})0.3V to +3.9V
Output Voltage (R_{OUT})0.3V to (V_{CC} + 0.3V)
Storage Temperature Range65°C to +150°C
ESD Rating

Note: Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Recommended Operating Conditions

	Min.	Тур.	Max.	Units
Supply Voltage (V _{CC})	3	3.3	3.6	
High Level Input Voltage, V_{IH}	2			
Low Level Input Voltage, V _{IL}			0.8	
Magnitude of Differential Input Voltage V_{ID}	0.1		0.6	V
Common-mode Input Voltage, V_{1C} (Fig 5)	V _{ID} /2		2.4 - V _{ID} /2	
			V _{CC} -0.8	
Operating Free Air Temperature T_A	-40		85	°C

Electrical Characteristics (Over recommended operating conditions unless otherwise noted).

Parameter	Test Condition	Min.	Typ. ⁽¹⁾	Max.	Units
I _{CC} ⁽²⁾ Supply Current	No receiver load, Driver $R_L = 100$ ohms		8.0	10.8	mA

Notes:

1. All typical values are at 25°C with a 3.3V supply

2. I_{CC} measured with all TTL input. $V_{IN} = V_{CC}$ or GND.

Electrical Characteristics (Over recommended operating conditions unless otherwise noted).

	Parameter	Test Conditions	Min.	Тур.	Max.	Units
V _{OD}	Differential output voltage magnitude	$R_{1} = 100 \text{ ohms}$	247	390	470	
$\Delta V_{\text{OD}} $	Change in differential output voltage magnitude between logic states	See Figures 1 and 2	-50		50	mV
V _{OC(SS)}	Steady-state common-mode output voltage		1.125	1.25	1.375	V
$\Delta V_{OC(SS)}$	Change in steady-state common-mode output voltage between logic states	See Figure 3	-50		50	mV
V _{OC(PP)}	Peak-to-peak common-mode output voltage			50	150	

	Parameter		Test Conditions	Min.	Тур.	Max.	Units
I _{IH}	High-level input current	D _{IN}	$V_{IH} = 5V$		2	20	
I _{IL}	Low-level input current	D _{IN}	$V_{IL} = 0.8V$		2	10	μA
т	Chart singuit autout surrout		V_{OY} or $V_{OZ} = 0V$		-6	-9	
I _{OS}	Short-circuit output current		$V_{OD} = 0V$		-8	-11	mA
I _{O(OFF)}	Power-off output current		$V_{\rm CC} = 0V, V_{\rm O} = 3.6V$			±1	μΑ
C _{IN}	Input capacitance				7		pF

Receiver Electrical Characteristics (Over recommended operating conditions unless otherwise noted).

Parameter		Test Conditions	Min.	Тур.	Max.	Units
$\mathbf{V}_{\mathrm{ITH^{+}}}$	Positive-going differential input voltage threshold	Saa Figuraa 4 & Tabla 1			50	mV
V _{ITH-}	Negative-going differential input voltage threshold	See Figures 4 & Table 1	-50			III V
V _{он}	High-level output voltage	$I_{OH} = -8mA$	2.4			V
V _{OL}	Low-level output voltage	$I_{OL} = 8mA$			0.4	V
T		$V_I = 0$	-2	-11	-20	
I	Input current (R_{IN+} or R_{IN-})	$V_{I} = 2.4V$	-1.2	-3		
I _{I (OFF)}	Power-off input current (R_{IN+} or R_{IN-})	$V_{\rm CC} = 0$			±20	μA
I _H	High-level input current (enables)	$V_{IH} = 2V$			±10	
IL	Low-level input current (enables)	$V_{IL} = 0.8V$			±10	
С	Input capacitance			5		pF

Note: All typical values are at 25°C with a 3.3V supply

	Parameter		Min.	Typ. ⁽¹⁾	Max.	Units
$\mathbf{t}_{\mathrm{PLH}}$	Propagation delay time, low-to-high-level output			1.9	2.5	
t _{PHL}	Propagation delay time, high-to-low-level output	$R_{\rm L} = 100 \text{ ohms}$		1.9	2.5	ns
tr	Differential output signal rise time	$C_L = 10 pF$ See Figure 2		0.6	1.1	
t _f	Differential output signal fall time	See Figure 2		0.6	1.1	
t _{sk(p)}	Pulse skew (t_{PHL} - t_{PLH})			270		ps
t _{sk(pp)}	Part-part skew ⁽²⁾				0.9	ns

Driver Switching Characteristics (Over recommended operating conditions unless otherwise noted).

Notes:

1. All typical values are at 25°C with a 3.3V supply.

2. t_{sk(pp)}: magnitude of difference in propagation delay times between any specific terminals of two devices (all things being equal).

Receiver Switching Characteristics (Over recommended operating conditions unless otherwise noted).

Parameter		Test Conditions	Min.	Typ. ⁽¹⁾	Max.	Units
$t_{\rm PLH}$	Propagation delay time, low-to-high-level output			2.0	3.1	
t _{PHL}	Propagation delay time, lhigh-to-low-level output			2.2	3.1	ns
t _{sk(pp)} ⁽²⁾	Part-part skew ⁽²⁾	$C_L = 10 \text{pF}$			1.3	
t _{sk(p)}	Pulse skew $(t_{PHL} - t_{PLH})$	See Figure 5		300	500	ps
t _r	Output signal rise time			0.9	1.5	ns
$t_{\rm f}$	Output signal fall time			1.0	1.8	ns

Notes:

1. All typical values are at 25°C with a 3.3V supply

2. t_{sk(pp)}: magnitude of difference in propagation delay times between any specific terminals of two devices (all things being equal)

Parameter Measurement Information

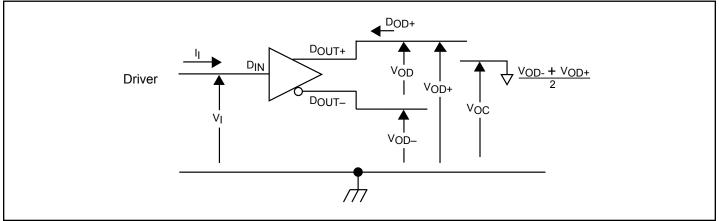


Figure 1. Driver Voltage and Current Definitions

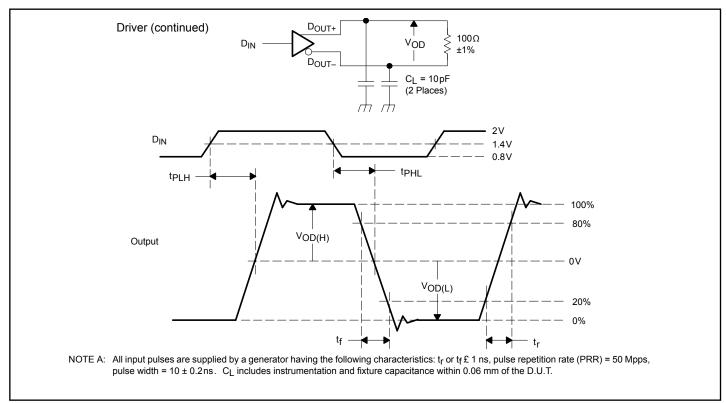


Figure 2. Test Circuit, Timing, and Voltage Definitions for the Differential Output Signal

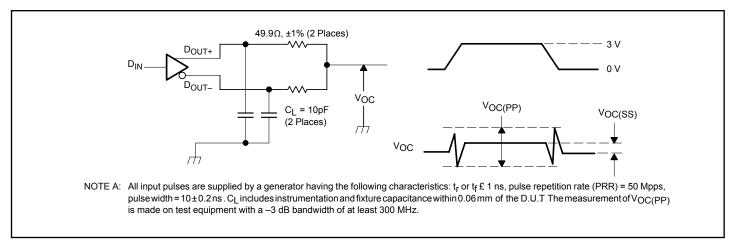


Figure 3. Test Circuit and Definitions for the Driver Common-Mode Output Voltage

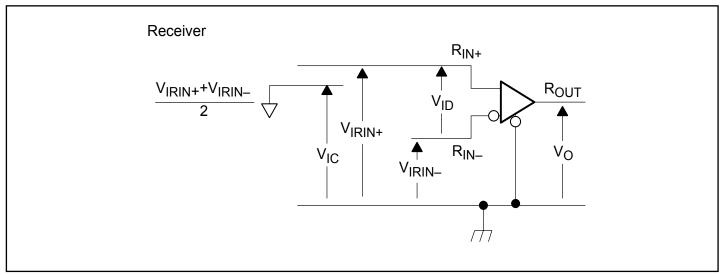


Figure 4. Receiver Voltage Definitions

APPLIED \ (\		RESULTING DIFFERENTIAL INPUT VOLTAGE (mV)	RESULTING COMMON- MODE INPUT VOLTAGE (V)
V _{IRIN+}	V _{IRIN+}	V _{ID}	V _{IC}
1.225	1.175	50	1.2
1.175	1.225	-50	1.2
2.375	2.325	50	2.35
2.325	2.375	-50	2.35
0.1	0	50	0.05
0	0.05	-50	0.05
1.5	0.9	600	1.2
0.9	1.5	-600	1.2
2.4	1.8	600	2.1
1.8	2.4	-600	2.1
0.6	0	600	0.3
0	0.6	-600	0.3

Table 1. Receiver Minimum and Maximum Input Threshold Test Voltages

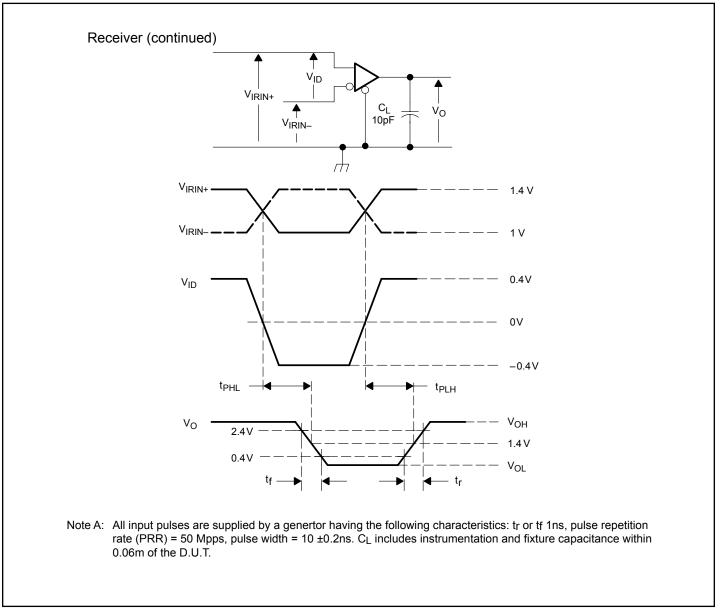
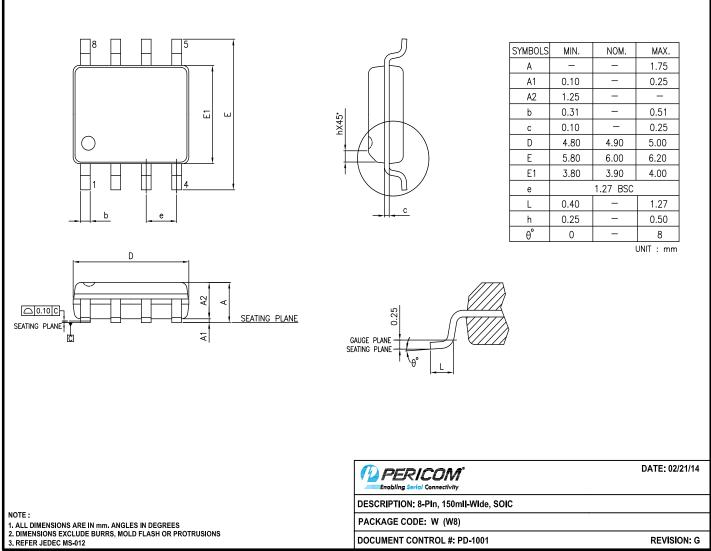


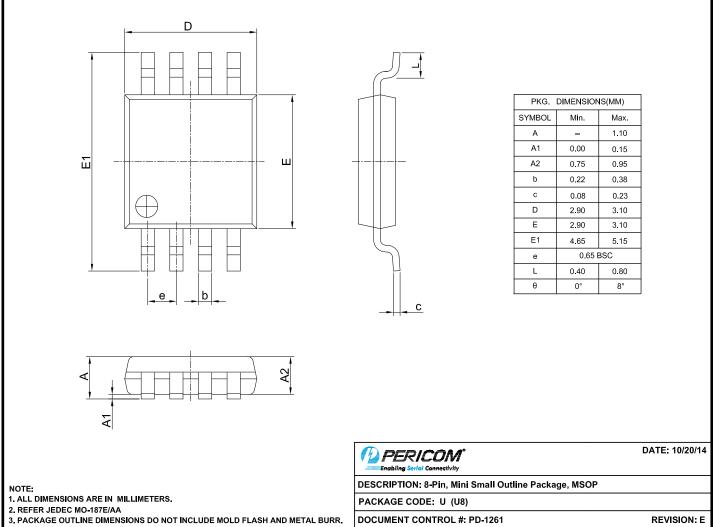
Figure 5. Timing Test Circuit and Waveforms

Packaging Mechanical: 8-Pin SOIC (W)



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Packaging Mechanical: 8-Pin MSOP (U)



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Note: For latest package info, please check: http://www.pericom.com/support/packaging/packaging-mechanicals-and-thermal-characteristics/

Ordering Information

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Ordering Number	Package Code	Package Description
PI90LV179WE	W	8-Pin, 150mil-Wide (SOIC)
PI90LV179WEX	W	8-Pin, 150mil-Wide (SOIC), Tape & Reel
PI90LV179UE	U	8-Pin, Mini Small Outline Package (MSOP)
PI90LV179UEX	U	8-Pin, Mini Small Outline Package (MSOP), Tape & Reel

Notes:

• Thermal characteristics can be found on the company web site at www.pericom.com/packaging/

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• E = Pb-free and Green

• X suffix = Tape/Reel

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